ISA1235AC1 ISA1602AM1

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE

DESCRIPTION

ISA1235AC1 ISA1602AM1 is super mini package resin sealed silicon PNP epitaxial type transistor.

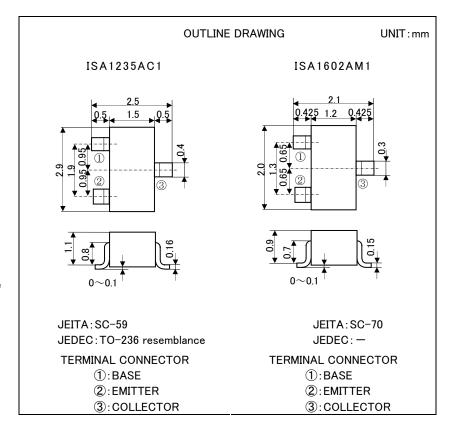
These are designed for low frequency voltage amplify application .

FEATURE

- •Excellent linearity of DC forward current gain.
- Small collector to emitter saturation voltage VCE(sat)=-0.3Vmax

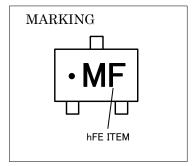
APPLICATION

For small type machine low frequency voltage amplify application.



MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings		UNIT
		ISA1235AC1	ISA1602AM1	CINII
V _{CBO}	Collector to Base voltage	-60		V
V_{EBO}	Collector to Emitter voltage	-6		V
V_{CEO}	Emitter to Base voltage	-50		V
I c	Collector current	-200		mA
P_{c}	Collector dissipation	200		mW
Tj	Junction temperature	+150		°C
Tstg	Storage temperature	−55 ~ +150		°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

Symbol	Parameter	Test conditions	Limits			LINIT
			Min	Ave	Max	UNIT
$V_{(BR)CEO}$	Collector to Emitter Breakdown voltage	I _C =−100 μ A, R _{BE} =∞	-50			V
I _{CBO}	Collector cut off current	V_{CB} =-60V, I _E =0			-0.1	μΑ
I _{EBO}	Emitter cut off current	V_{EB} =-6V, I $_{C}$ =0			-0.1	μΑ
h _{FE} *	DC forward current gain	V_{CE} =-6V, I _C =-1mA	150		500	_
h _{FE}	DC forward current gain	V_{CE} =-6V, I _C =-0.1mA	90			_
$V_{CE(sat)}$	Collector to Emitter saturation voltage	I _C =-100mA, I _B =-10mA			-0.3	V
f _T	Gain bandwidth product	V_{CE} =-6V, I _E =10mA		200		MHz
Cob	Collector output capacitance	V_{CB} =-6V, I _E =0,f=1MHz		4.0		pF
NF	Noise Figure	$V_{CE} = -6V$, $I_{E} = 0.3 \text{mA}$, $f = 100 \text{Hz}$, $RG = 10 \text{k} \Omega$			20	dB

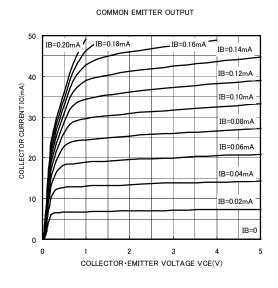
^{*:} It shows hFE classification in below table.

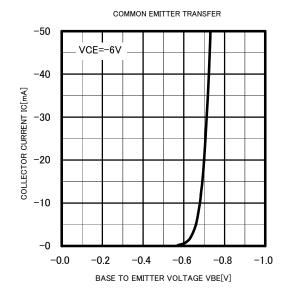
	E	F
hFE	150~300	250~500

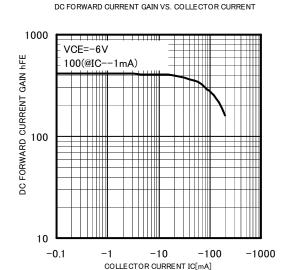
ISA1235AC1 ISA1602AM1

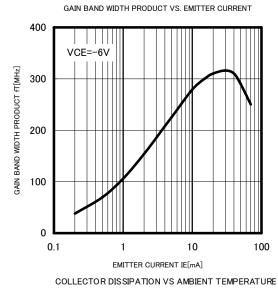
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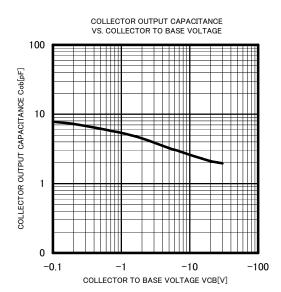
TYPICAL CHARACTERISTICS

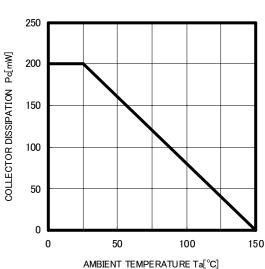






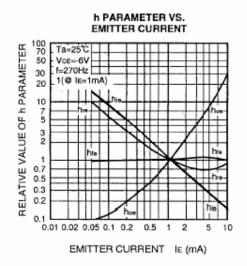


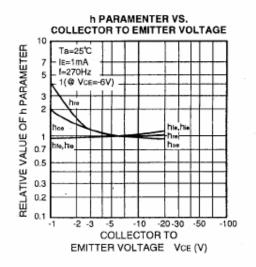




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COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hie	Closed loop small signal input impedance	Ta=25°C	7.0	kΩ
hre	Open loop small signal reverse voltage amplification factor	Vce=-6V	0.1	X10-3
hte	Closed loop small signal forward current amplification factor	IE=1mA	250	
hos	Open loop small signal output admittance	f=270Hz	18	μS



Marketing division, Marketing planning department 6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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